PatientID: HDR51

Okitobba 06, 2023

## Color Code

HR: High-Level Resistance
LR: Low-Level Resistance
IR: Intermediate Resistance

S: Susceptible

DRUG.CLASS	DRUG	RESISTANCE.PROFILE	DRMS.above.20.percent.prevalence
PI	ATV	$\mathbf{S}$	
	DRV	${f S}$	
	FPV	${f S}$	
	IDV	$\mathbf{S}$	
	LPV	S	
	NFV	S	
	SQV	$\mathbf{S}$	
	TPV	$\mathbf{S}$	
NRTI	ABC	IR	
	AZT	${f S}$	
	D4T	$\operatorname{IR}$	
	DDI	IR	M184MV;D67N;K70E
	FTC	$_{ m HR}$	
	LMV	$_{ m HR}$	
	TDF	$\operatorname{LR}$	
NNRTI	DOR	$_{ m HR}$	
	EFV	$_{ m HR}$	
	ETR	$\operatorname{LR}$	Y188L;V179D
	NVP	$_{ m HR}$	
	RPV	$_{ m HR}$	

## Appendix

## Drug abbreviations in full

DRUG.CLASS	ABBREVIATION	DRUG.NAME
	ATV	Atazanavir
	DRV	Darunavir
	FPV	Fosamprenavir
PI	IDV	Indinavir
11	LPV	Lopinavir
	NFV	Nelfinavir
	SQV	Saquinavir
	TPV	Tipranavir
	ABC	Abacavir
	AZT	Azidothymidine
	DFT	Stavudine
NRTI	DDI	Didanosine
	FTC	Emtricitabine
	LMV	Lamivudine
	TDF	Tenofovir
	DOR	Doravirine
	EFV	Efavirenz
NNRTI	ETR	Etravirine
	NVP	Nevirapine
	RPV	Rilpivirine
	BIC	Bictegravir
	CAB	Cabotegravir
INSTI	DTG	Dolutegravir
	EVG	Elvitegravir
	RAL	Raltegravir

## Comments

DRUG.CLASS	COMMENTS
PI	
	D67N is a non-polymorphic TAM associated with low-level resistance to AZT.
NRTI	K70/E/Q/N/T/S/G cause low-leve resistance to ABC and TDF.
	M184V/I cause high-level in vitro resistance to 3TC and FTC and low/intermediate
	resistance to ABC (3-fold reduced susceptibility). M184V/I are not contraindications to
	continued treatment with 3TC or FTC because they increase susceptibility to AZT and
	TDF and are associated with clinically significant reductions in HIV-1 replication.
	V179D/E are somewhat polymorphic accessory NNRTI-selected mutation. In combination
	with other NNRTI DRMs, they appear to contribute low-levels of reduced susceptibility to
	each of the NNRTIs. In particular, the combinations of K103R/V179D and V106I/V179D
NNRTI	act synergistically to reduce NVP and EFV susceptibility.
	Y188L is a non-polymorphic mutation that confers high-level resistance to NVP, EFV,
	RPV, and DOR, and potentially low-level resistance to ETR.
INSTI	